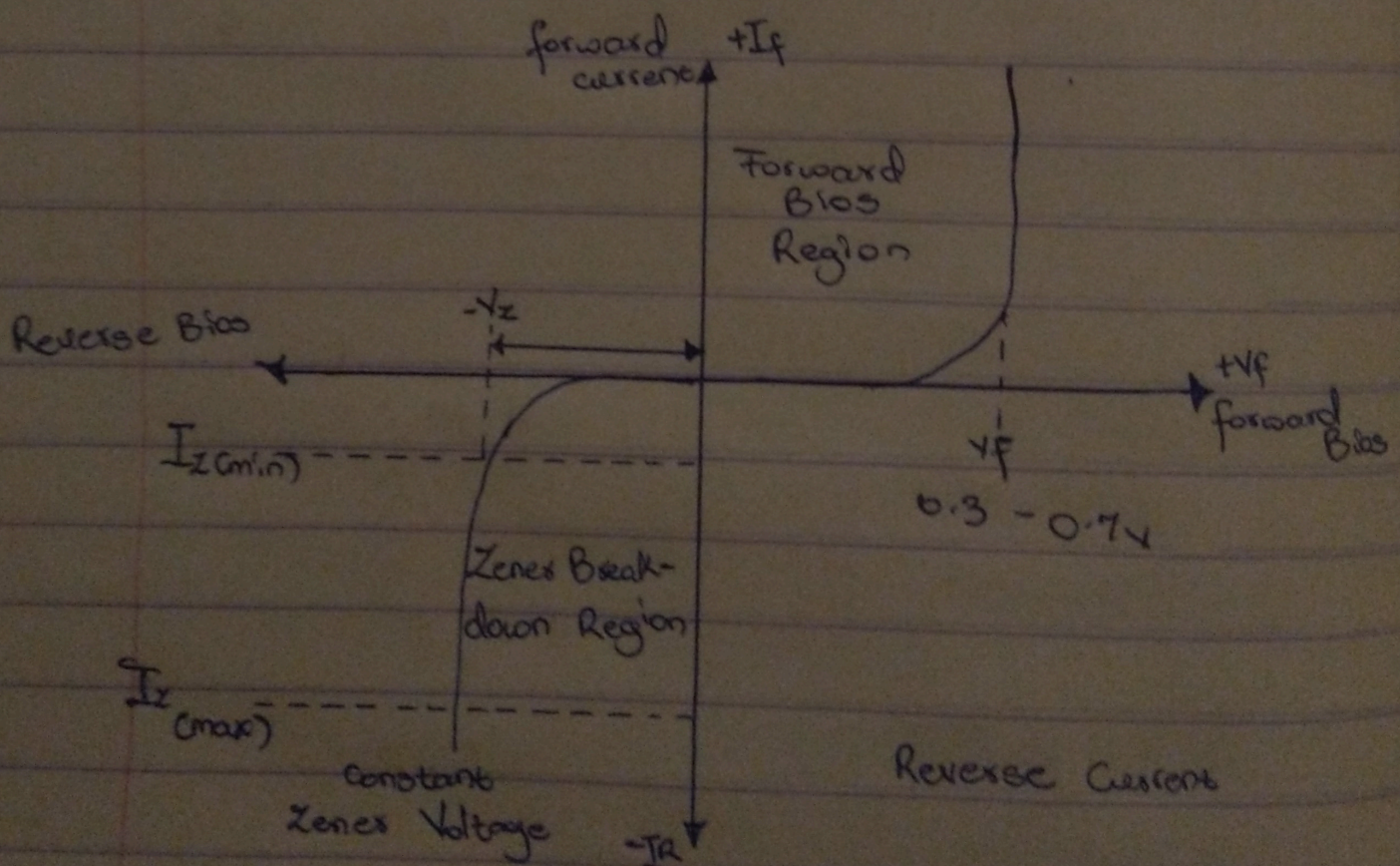
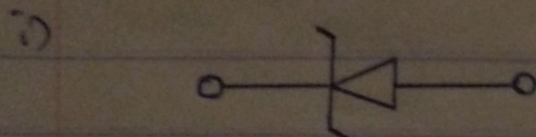
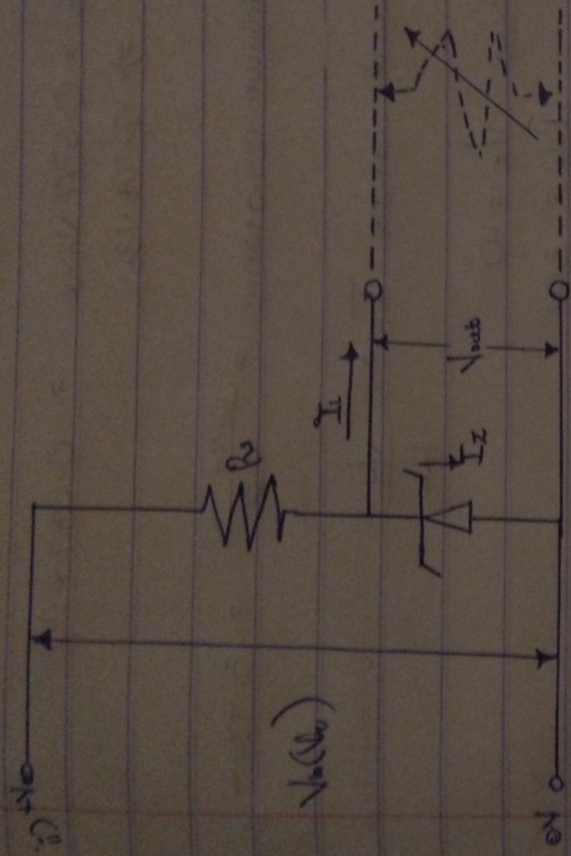


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i) A Zener diode is a diode similar to the standard PN junction diode but they are especially designed to have a low and specified Reverse Breakdown Voltage



I-V characteristic Curve



where,

R_S = Resistor

V_S = Voltage Source

V_{out} = Stabilized output Voltage

R_L = Load Resistance

I_Z = Load current across zener diode

2) Max Power = 5W $I_Z = 500\text{mA} = 0.5\text{A}$, $20\text{V}_{max} = V_S$

∴ Maximum Current = $\frac{\text{Max Power}}{\text{Voltage}} = \frac{5\text{W}}{10\text{V}} \rightarrow 0.5\text{A}$

$V_Z = 10\text{ volts}$

Minimum resistance = $\frac{V_S - V_Z}{I_Z}$

$$V_{dc} = 0.637 V_{max} = 0.637 \times 20$$

$$\Rightarrow 12.74 V_{dc}$$

$$\text{Minimum resistance} = \frac{12.74 - 10}{0.5} = 5.48 \Omega$$

$$\text{(ii) Load current } I_L = \frac{V_Z}{R_L}$$

$$\text{where } V_Z = 10$$

$$R_L = 500$$

$$\Rightarrow \frac{10}{500} \uparrow 0.02 A \text{ or } 20 mA$$